NSN 5961-01-508-7032

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-508-7032 **Inclosure Material:** Plastic **Overall Length:** Between 0.336 inches and 0.344 inches **Overall Height:** Between 0.053 inches and 0.069 inches Overall Width: Between 0.228 inches and 0.244 inches **End Application:** Core b install **Component Name And Quantity:** 8 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage all semiconductor device diode and 90.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current preset single semiconductor device diode **Power Rating Per Characteristic:** 1500.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: